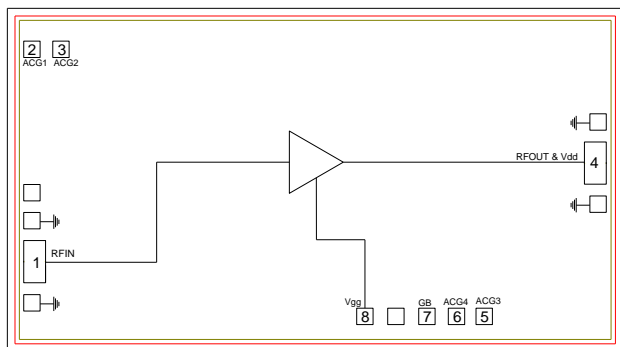


### Product Overview

The CMD249 is wideband GaAs MMIC distributed power amplifier die which operates from DC to 20 GHz. The amplifier delivers greater than 12 dB of gain with a corresponding output 1 dB compression point of +30 dBm and output IP3 of 38 dBm at 10 GHz. The CMD249 is a 50 ohm matched design which eliminates the need for RF port matching. The CMD249 offers full passivation for increased reliability and moisture protection.

### Functional Block Diagram



### Key Features

- Ultra Wideband Performance
- High Linearity
- High Output Power
- Excellent Return Losses
- Small Die Size

### Ordering Information

Part No.	Description
CMD249	DC - 20 GHz Distributed Power Amplifier, 25 Piece Gel Pack

### Electrical Performance ( $V_{dd} = 10.0\text{ V}$ , $V_{gg} = -0.95\text{ V}$ , $T_A = 25\text{ }^{\circ}\text{C}$ , $F = 10\text{ GHz}$ )

Parameter	Min	Typ	Max	Units
Frequency Range		DC - 20		GHz
Gain		13		dB
Noise Figure		3.4		dB
Input Return Loss		16		dB
Output Return Loss		17		dB
Output P1dB		30		dBm
Supply Current		400		mA

## Absolute Maximum Ratings

Parameter	Rating
Drain Voltage, $V_{dd}$	10.5 V
Gate Voltage, $V_{gg}$	-2.0 to 0 V
RF Input Power	+30 dBm
Channel Temperature, $T_{ch}$	150 °C
Power Dissipation, $P_{diss}$	4 W
Thermal Resistance, $\theta_{JC}$	16.25 °C/W
Operating Temperature	-55 to 85 °C
Storage Temperature	-55 to 150 °C

Exceeding any one or combination of the maximum ratings may cause permanent damage to the device.

## Recommended Operating Conditions

Parameter	Min	Typ	Max	Units
$V_{dd}$	8.0	10.0	10.5	V
$I_{dd}$	350	400	450	mA
$V_{gg}$		-0.95		V
$I_{gg}$		-2.5		mA

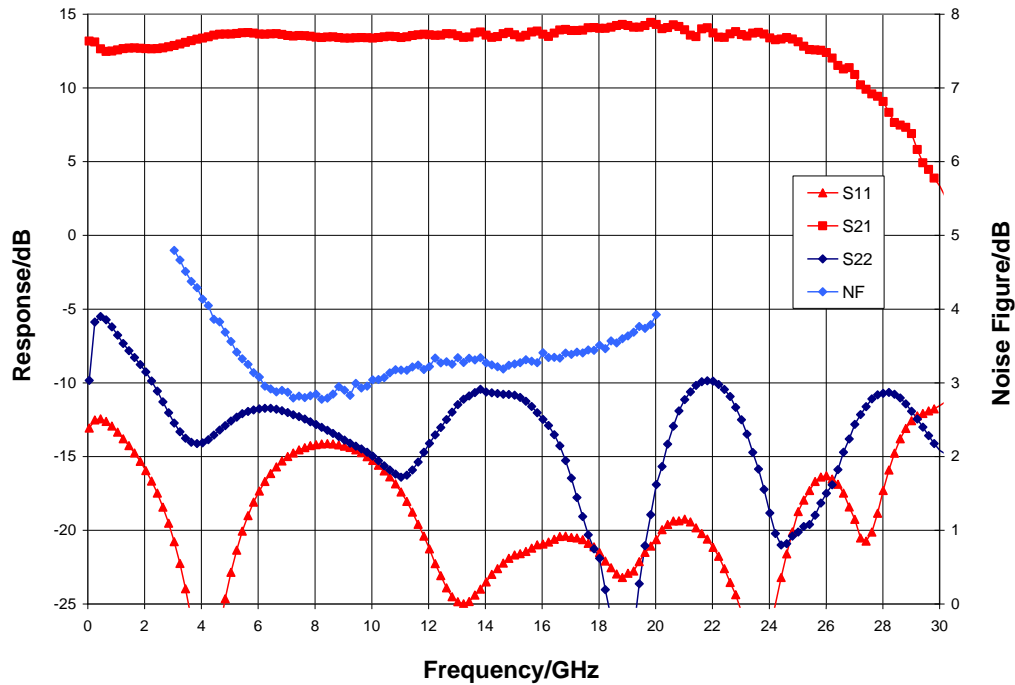
Electrical performance is measured at specific test conditions.  
Electrical specifications are not guaranteed over all recommended operating conditions.

## Electrical Specifications ( $V_{dd} = 10.0$ V, $V_{gg} = -0.95$ V, $T_A = 25$ °C)

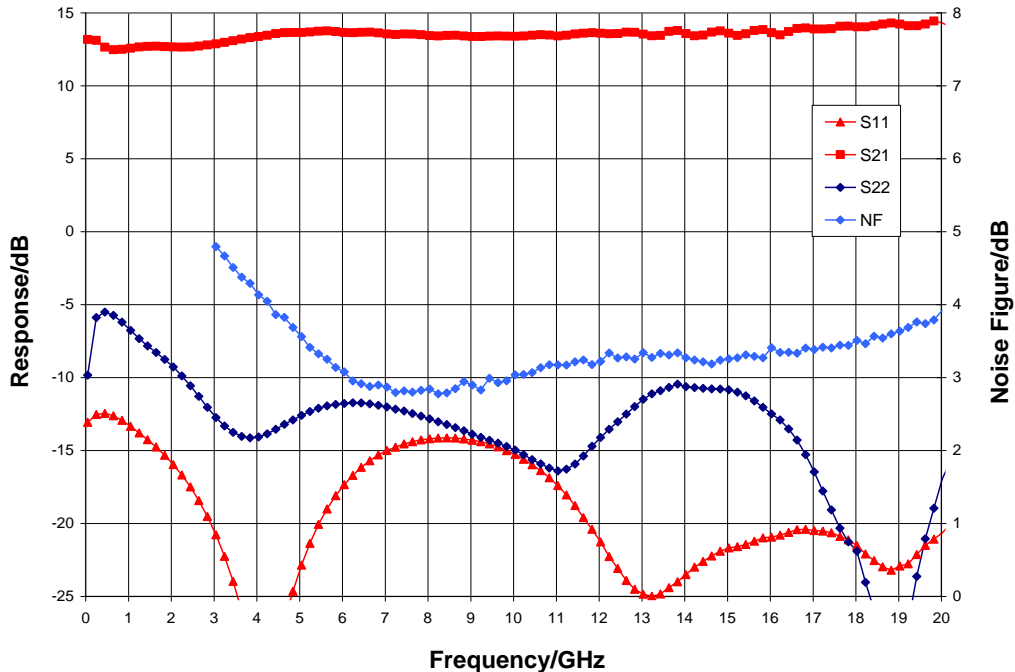
Parameter	Min	Typ	Max	Min	Typ	Max	Units
Frequency Range		DC - 6			6 - 20		GHz
Gain	10.5	13		11	13.5		dB
Noise Figure		5			3.5		dB
Input Return Loss		15			17		dB
Output Return Loss		10			18		dB
Output P1dB	28	30		27	29.5		dBm
Output IP3		40			35		dBm
Supply Current	300	400	500	300	400	500	mA
Gain Temperature Coefficient		0.009			0.014		dB/°C
Noise Figure Temperature Coefficient		0.01			0.012		dB/°C

## Typical Performance

Broadband Performance,  $V_{dd} = 10\text{ V}$ ,  $V_{gg} = -0.95\text{ V}$ ,  $I_{dd} = 400\text{ mA}$ ,  $T_A = 25\text{ °C}$

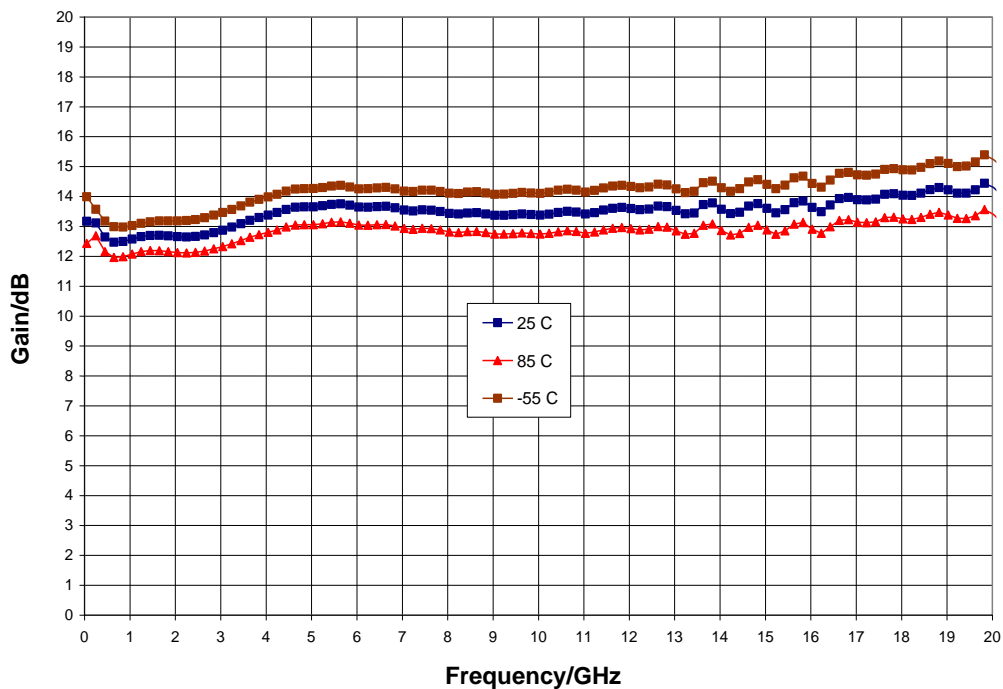


Narrow-band Performance,  $V_{dd} = 10\text{ V}$ ,  $V_{gg} = -0.95\text{ V}$ ,  $I_{dd} = 400\text{ mA}$ ,  $T = 25\text{ °C}$

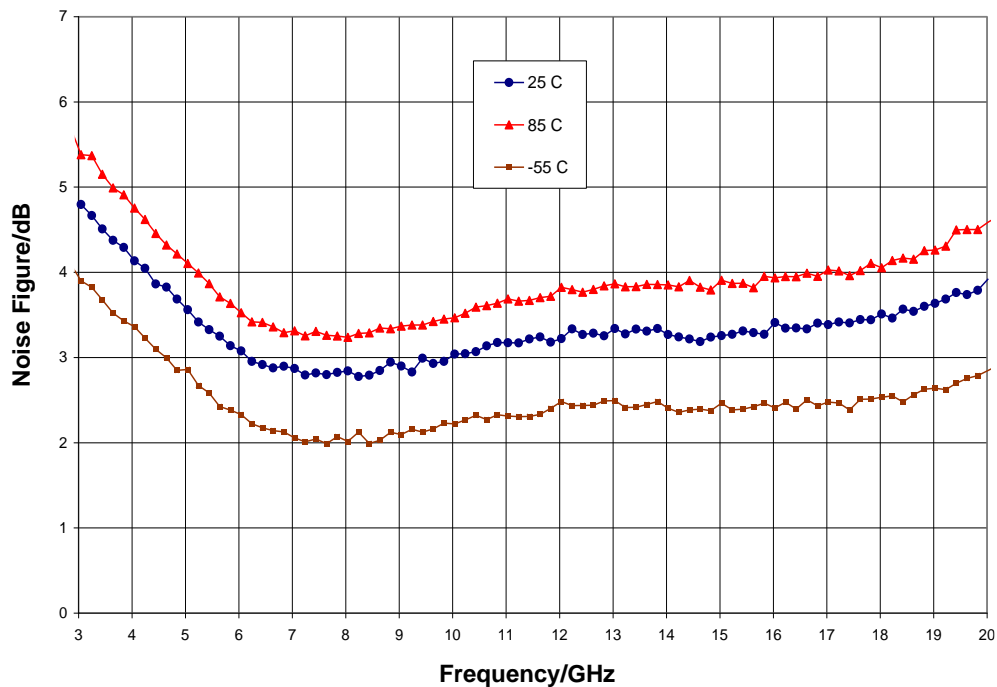


## Typical Performance

Gain vs. Temperature,  $V_{dd} = 10\text{ V}$ ,  $V_{gg} = -0.95\text{ V}$

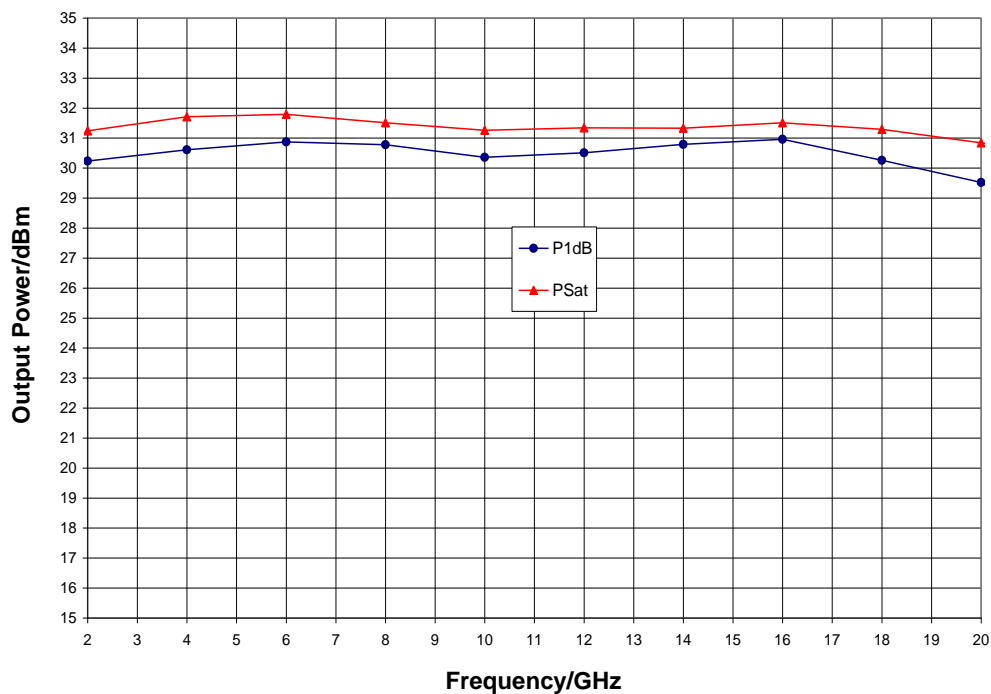


Noise Figure vs. Temperature,  $V_{dd} = 10\text{ V}$ ,  $V_{gg} = -0.95\text{ V}$

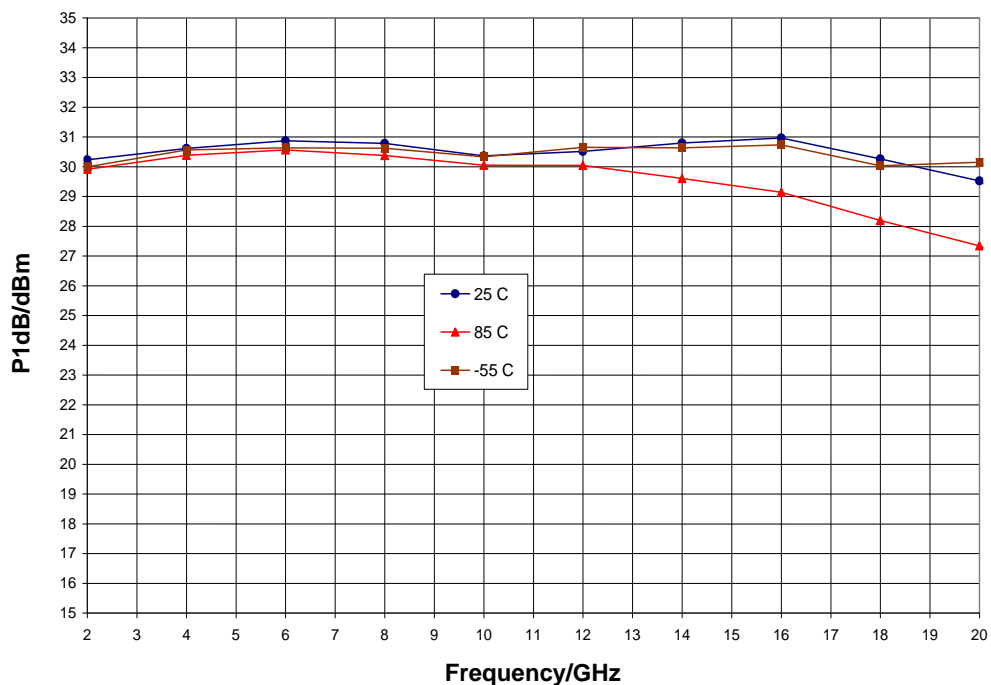


## Typical Performance

Output Power,  $V_{dd} = 10\text{ V}$ ,  $V_{gg} = -0.95\text{ V}$ ,  $T_A = 25\text{ °C}$

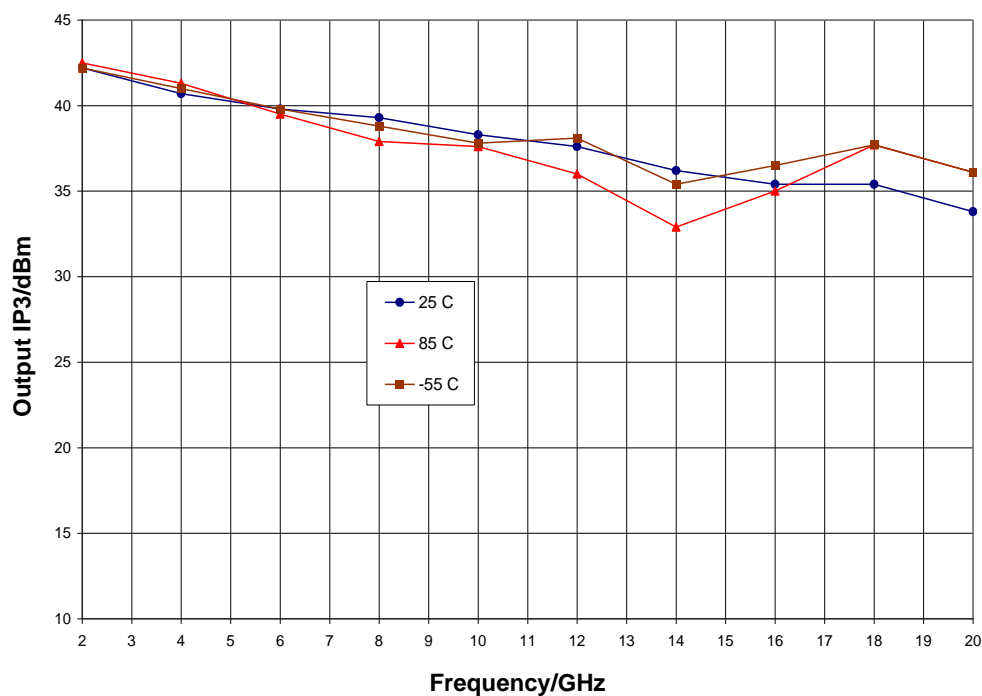


P1dB vs. Temperature,  $V_{dd} = 10\text{ V}$ ,  $V_{gg} = -0.95\text{ V}$



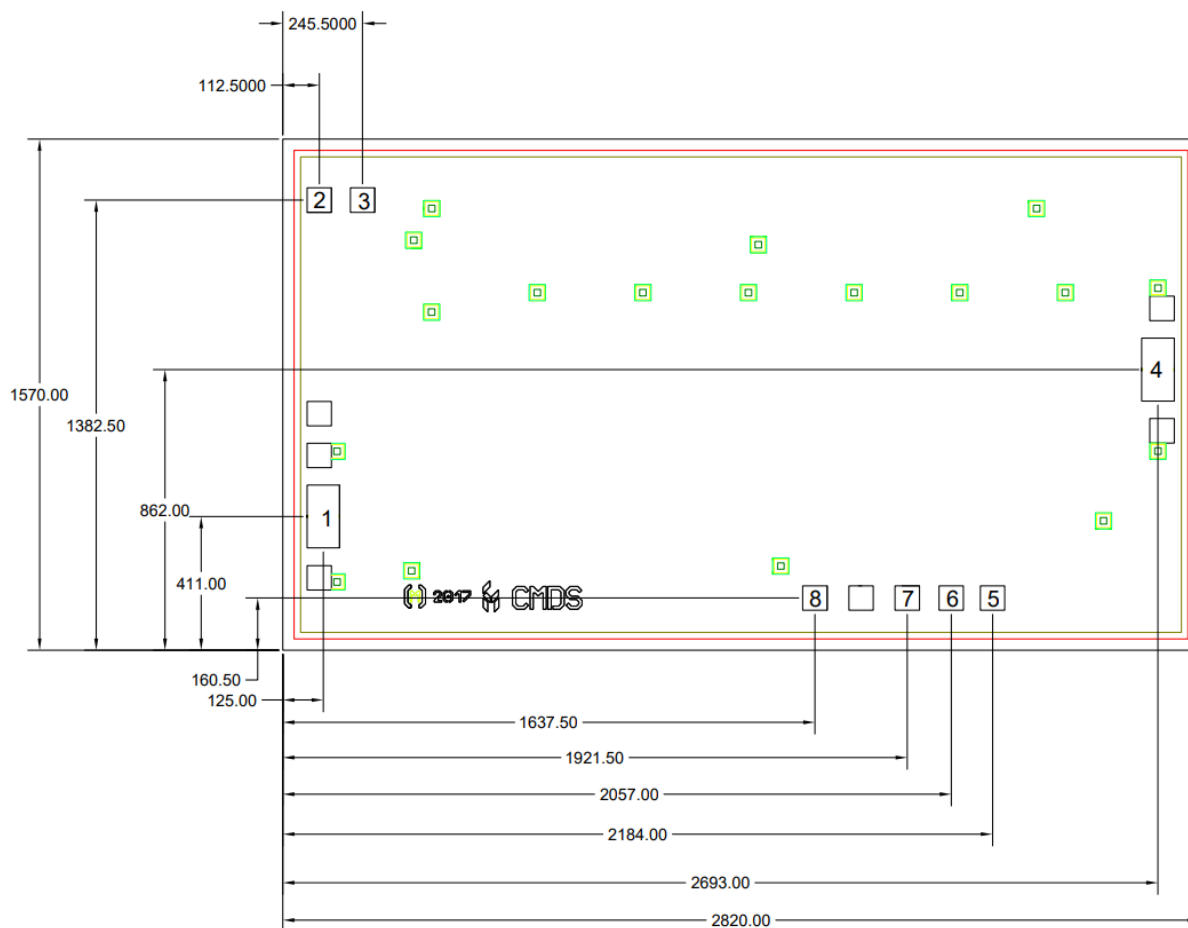
## Typical Performance

Output IP3 vs. Temperature,  $V_{dd} = 10\text{ V}$ ,  $V_{gg} = -0.95\text{ V}$



## Mechanical Information

Die Outline (all dimensions in microns)



Notes:

1. No connection required for unlabeled pads
2. Backside is RF and DC ground
3. Backside and bond pad metal: Gold
4. Die is 70 microns thick
5. DC bond pads (2, 3, 5, 6, 7, and 8) are 78 microns square
6. RF bond pads (1 and 4) are 108 x 193 microns

## Pad Description

### Pad Diagram



### Functional Description

Pad	Function	Description	Schematic
1	RF in	50 ohm matched input	
2, 3	ACG1, 2	Low frequency termination Attach bypass capacitor per application circuit	
4	RF out & V <sub>dd</sub>	Power supply voltage and 50 ohm matched output	
5, 6	ACG3, 4	Low frequency termination Attach bypass capacitor per application circuit	
7	GB	Connect to DC ground	
8	V <sub>gg</sub>	Power supply voltage Decoupling and bypass caps required	
Backside	Ground	Connect to RF / DC ground	



## Applications Information

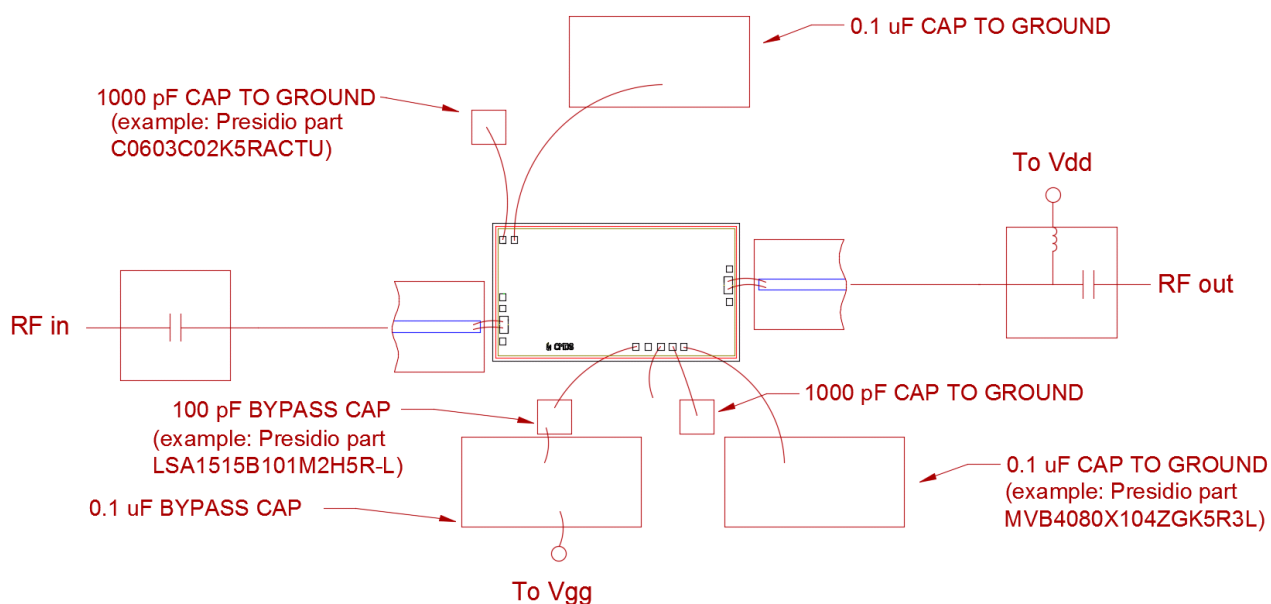
### Assembly Guidelines

The backside of the CMD249 is RF ground. Die attach should be accomplished with electrically and thermally conductive epoxy only. Eutectic attach is not recommended. Standard assembly procedures should be followed for high frequency devices. The top surface of the semiconductor should be made planar to the adjacent RF transmission lines, and the RF decoupling capacitors placed in close proximity to the DC connections on chip.

RF connections should be made as short as possible to reduce the inductive effect of the bond wire. Use of a 0.8 mil thermosonic wedge bonding is highly recommended as the loop height will be minimized. The RF input and output require a double bond wire as shown.

The semiconductor is 70  $\mu\text{m}$  thick and should be handled by the sides of the die or with a custom collet. Do not make contact directly with the die surface as this will damage the monolithic circuitry. Handle with care.

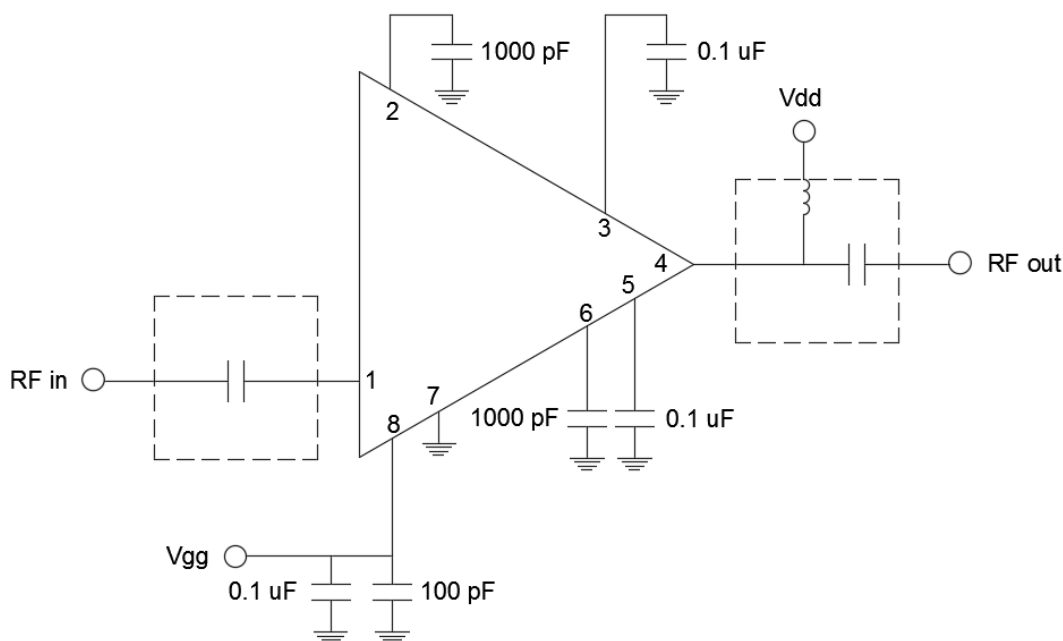
### Assembly Diagram



**GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.**

## Applications Information

### Application Circuit



Note: Drain voltage ( $V_{dd}$ ) must be applied through a broadband bias tee or external bias network.  
External DC block is required on RF input.

### Biasing and Operation

The CMD249 is biased with a positive drain supply and a negative gate supply. Performance is optimized when the drain voltage is set to +10 V. The nominal gate voltage is -0.95 V.

Turn ON procedure:

1. Apply gate voltage  $V_{gg}$  and set to -2 V
2. Apply drain voltage  $V_{dd}$  and set to +10 V
3. Increase  $V_{gg}$  (less negative) to achieve a drain current of 400 mA

Turn OFF procedure:

1. Turn off drain voltage  $V_{dd}$
2. Turn off gate voltage  $V_{gg}$

RF power can be applied at any time.

## Handling Precautions

Parameter	Rating	Standard
ESD – Human Body Model (HBM)	Class 1A	ESDA / JEDEC JS-001-2012



Caution!  
ESD-Sensitive Device

## RoHS Compliance

This part is compliant with 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Lead Free
- Antimony Free
- TBBP-A (C<sub>15</sub>H<sub>12</sub>Br<sub>4</sub>O<sub>2</sub>) Free
- SVHC Free
- Halogen Free
- PFOS Free

## Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

Web: [www.qorvo.com](http://www.qorvo.com)

Tel: 1-844-890-8163

Email: [customer.support@qorvo.com](mailto:customer.support@qorvo.com)

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